

CVD routes to MgB_2 conductors

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(February 2, 2008)

Abstract

Processing methods are described for the development of magnesium diboride wire using the chemical vapor deposition (*CVD*) to produce long lengths of suitably doped starting boron fiber. It is found that titanium can be co-deposited with the boron to make long lengths of doped fiber that contain both TiB and TiB_2 . When this fiber is reacted in Mg vapor to transform boron into MgB_2 , the resulting conductor has a superconducting critical current density of about 5×10^6 A/cm² at 5 K and self field. The critical current density at 25 K and 1 Tesla is 10,000 A/cm². Using optical methods to define grain boundaries and energy dispersive X-rays to determine Ti and Mg concentration, these samples show a fine dispersion of Ti through out the grains and no conspicuous precipitation of TiB_2 on the MgB_2 grain boundaries. This is to be contrasted with the precipitation of TiB_2 on MgB_2 grain boundaries observed for samples prepared by solid state reaction of Ti , Mg , and B powders. Introducing Ti impurities into the B during the *CVD* deposition of the B gives a distribution of TiB_2 in the resulting MgB_2 different

from solid state reaction of powders.

74.25.Bt, 74.25.Fy, 74.25.Ha

I. INTRODUCTION

The discovery¹ of superconductivity in MgB_2 at 39.2 K opens some very interesting opportunities for practical applications of this material as a conductor in power applications.² Typically, the operating temperature of these conductors would be at about half the superconducting transition temperature, T_c , or about 20 K where closed cycle refrigerators are quite efficient. Early studies of the temperature and magnetic field dependence of the superconducting critical current density, J_c ,³ indicated that grain boundaries in this material would carry very substantial supercurrents, $5 \times 10^5 A/cm^2$, in conductors prepared in a variety of ways.^{4,5} In addition, a very early attempt to explore the use of powder-in-tube methods by Jin and co-workers⁶ showed that practical conductors are feasible.

On the fundamental side, the measurement of an isotope⁷ effect with $\alpha = 0.26$ where $T_c \sim M^{-\alpha}$ and M is the isotopic mass of the boron atom indicated that phonons play a major role in the superconducting interaction in MgB_2 . For clean samples, resistivity measurements at 40 K indicated that $\rho \sim 1.0 \mu\Omega\text{-cm}$ which, combined with the calculated Fermi velocity,⁸ $v_F \sim 4.7 \times 10^6 m/s$, gives a mean-free-path, $\ell \sim 60 nm$. From the measured upper critical field, $H_{c2} = 16 T$,⁹ the coherence distance of a clean sample can be determined from $H_{c2} = \Phi_o/[2\pi\xi_o^2]$ to be $\xi_o \sim 5 nm$. Here, Φ_o is the flux quantum. With ℓ substantially greater than ξ_o , these materials are in the clean limit. Several groups^{4,5} found J_c values in the range of 500,000 A/cm^2 in self field at 5 K , but these values fell below 1,000 A/cm^2 at 1 T at 5 K . Broadly speaking, the irreversibility field, H_{irr} was roughly half of H_{c2} .

The primary drawback for this material appeared to be the relatively low values of the upper critical field, $H_{c2} = 16 T$,⁹ and the resulting rapid drop in J_c with field. The most straight forward way to raise H_{c2} is to shorten the mean-free-path, ℓ , which in turn shortens the coherence distance, $\xi = \sqrt{\xi_o\ell}$. Thus $H_{c2} = \Phi_o/[2\pi\xi^2]$ would rise with decreasing ℓ . The introduction of point defects is an effective way to raise H_{c2} . In pure MgB_2 , the volume pinning force seems to decrease as $[1 - H/H_{irr}]^2$ indicating that grain boundary pinning dominates.⁴ Hence, reducing the grain size should help. Alternatively, the strength of the

pinning and J_c , can be increased by introducing precipitates. Typical dimensions might be an array of pinning sites with a characteristic dimension of the coherence distance, $1 - 5 \text{ nm}$, and a spacing between pinning centers about 5 times larger.

Doping of MgB_2 has proven to be difficult because relatively few impurities go into the lattice in solid solution. Early reports by Slusky and co-workers¹⁰ show that Al added by reacting powders in a solid state reaction substitute for Mg in the MgB_2 lattice. There is a smooth change in lattice parameter and smooth decrease in T_c for $Mg_{1-y}Al_yB_2$ for y out to 0.10 and then a two phase region is entered. At $y = 0.1$, T_c is still about 33 K and thus still relatively high.

For Ti doping by solid state reaction of powders, it appears that relatively little Ti is incorporated in the the MgB_2 grains. Work by Zhao and coworkers¹¹ showed that Ti appears as very thin layers of TiB_2 precipitates on the MgB_2 grain boundaries. Samples were made via solid state reaction by grinding the Ti , Mg , and B powders, pressing pellets, and heat treating. Microstructural analysis seemed to indicate that TiB_2 may act as a sintering agent leading to higher density, very fine MgB_2 grain-size of about 10 nm , and excellent grain-to-grain coupling. Some high resolution transmission electron microscopy evidence points to the thickness of some of these grain boundary layers being as low as one TiB_2 unit cell.¹¹ Because the Ti does not enter the unit cell, there is relatively little diminution in T_c and very substantial increases in the critical current density, J_c . Optimum doping was in the range of a Mg/Ti ratio of about 0.1. One of the more important outcomes of this work was the observation that the Ti seems to refine the grain structure to a grain size of about 10 nm .

For carbon doping, rather large amounts of carbon can replace boron in the structure. Takenobu and co-workers¹² found that carbon substitutes for boron in $MgB_{2-x}C_x$ out to $x \sim 0.06$ as indicated by a smooth decrease in a-axis lattice parameter from 0.3085 nm at $x = 0$ to 0.3070 nm at $x = 0.06$ while T_c drops from 38.2 K to about 34.8 K . There was relatively little change in the c-axis dimension. Here, samples were made by mixing powders of the elements and firing at 900°C for 2 h . At higher x -values, they found that the

(110) X-ray peak of MgB_2 broadens indicating two phases.¹² . Bharathi and co-workers,¹³ by contrast, found that reacting under high pressure Ar , permitted the extension of carbon content to $x = 0.5$. They find a relatively smooth depression of T_c from 39 K at $x = 0$ to about 26 K at $x = 0.5$. Using a somewhat different procedure, we have found that reacting B_4C with Mg vapor at $950^\circ C$ for 2 h gives a material with $T_c \sim 17 K$. In other work, the change in lattice constant and T_c with carbon content also has been reported to be somewhat less than these values.¹⁴

For Si doping, a solid state reaction of Mg and amorphous B powder with nano-size Si particles show substantial Mg_2Si lines in the X-ray data and relatively little diminution in the transition temperature to about 36 K .¹⁵ This seems to imply that very little Si seems to enter the MgB_2 structure. In an alternate preparation method, Cooley and co-workers¹⁶ have shown Mg can be reacted with SiB_6 at temperatures as low as $500^\circ C$ to give Mg_2Si precipitates in a MgB_2 matrix with $T_c = 37 K$. These preliminary experiments seem to indicate that the enhancements in flux pinning arise from Mg_2Si precipitates rather than Si substitution into the MgB_2 lattice.

The purpose of this review is to summarize progress in attempts to make MgB_2 conductors using a CVD method for depositing the starting boron material. There is a well established commercial scale method to make boron fiber in kilometer lengths for use in high strength composites. The primary goal of this work is to find ways to make doped boron fiber that will permit the preparation of long lengths of high performance MgB_2 conductor. Tasks include 1) the development of processing methods to convert pure boron fiber to MgB_2 , 2) the development of methods to dope the starting boron fiber with point defects that will raise the upper critical field, H_{c2} , 3) the development of boron fibers that will produce nano-scale precipitates in the MgB_2 , and 4) the development of methods to handle the brittle character of the superconductor.

Chemical vapor deposition of the starting boron is a particularly attractive route to materials preparation because the impurity atoms can possibly be introduced with atomic scale dispersion. Initial experiments have focussed on titanium-doping to produce small

TiB_2 precipitate pinning centers with the next step to be the introduction of carbon point defects to shorten the electronic mean free path.

In a typical deposition process for boron fibers, a conducting filament such as tungsten or a carbon coated commercial silicon carbide fiber is introduced into a long glass chamber through a Hg seal at a rate of a few cm/s . A flowing stream of BCl_3 and hydrogen gas move through the full length of the chamber. The fiber is heated electrically to temperatures in the $1100 - 1300^\circ C$ range, and the boron is deposited in the hot zone. If a suitable carrier gas can be mixed with this gas stream, then impurity atoms such as Ti or C can be co-deposited with the boron to form filaments that can subsequently be converted to impurity doped- MgB_2 . Critical current densities were measured via magnetization as reported earlier.³

II. CONVERSION OF PURE B-FIBER TO MAGNESIUM DIBORIDE

Soon after the discovery of superconductivity¹ in MgB_2 , small wire segments of commercial boron fiber were converted to MgB_2 .¹⁷ These wire segments were only a few cm long and rather fragile, but they showed exceptionally low resistivity of $0.4 \mu\Omega - cm$ at $40 K$ and a sharp superconducting transition at $39.2 K$. In a subsequent series of upper critical field measurements,^{9,17} H_{c2} vs T curves indicated an extrapolation to $H_{c2}(T = 0)$ of about $16 T$. Critical current densities, J_c for a $100 \mu m$ diameter pure boron fiber reacted in Mg vapor at $900^\circ C$ for $2 h$ are shown for both $5 K$ and $25 K$ in Fig. 1. At $5 K$, $J_c \sim 5 \times 10^5 A/cm^2$ in self field, and J_c is about $1000 A/cm^2$ at $2.5 T$. At $25 K$, $J_c \sim 2 \times 10^5 A/cm^2$ in self field, and J_c is about $1000 A/cm^2$ at $1.4 T$. Also shown on Fig. 1 are data for a sample made by depositing $25 \mu m$ of pure boron on a carbon substrate. The $5 K$ data are the open circles and the $25 K$ data are the solid triangles. Within the reproducibility of the experiments, the $100 \mu m$ pure boron fibers give the same J_c values as samples made from $25 \mu m$ of pure B on a C substrate within the accuracy of the measurement. For all samples, the reaction is carried out at a single temperature, and the time can then be adjusted to optimize J_c if that is desired.

A series of measurements were undertaken to determine the lowest temperatures where these boron fibers would transform to MgB_2 at a high rate. A sample reacted at $800^\circ C$ for 2 h , as shown in Fig. 2, shows a Mg region only part way across the boron fiber in the relatively light area near the edge of the filament. A more detailed analysis shows that this is a uniform wall of a high boron compound, MgB_x , progressing across the fiber. Energy dispersive spectra in the scanning electron microscope indicate that this phase has x near 6 or 7. Because this phase is not the study of this work, further analysis was not undertaken. For this time and temperature, essentially no MgB_4 or MgB_2 forms. The white core of the filament is W_2B_5 .

By contrast, if a similar pure boron fiber is heated in Mg vapor at $875^\circ C$ for 2 h , the fiber transforms to MgB_2 nearly everywhere as shown in Fig. 3. The darker gray areas are small regions of MgB_4 as shown by the EDS line scan along the line shown, where the circle with a cross is the starting point of the scan. The large dip in Mg count rate is the W_2B_5 core and the 30 percent dip in count rate to the left of the core illustrates the decrease in Mg density going from MgB_2 to MgB_4 . Also visible in the micrograph are several faults along the edge of the fiber and a large void near the right end of the portion of the W_2B_5 core. The filament is not completely flat, so that the W_2B_5 core does not show along the entire length of the filament for this particular depth of polish. These flaws are typical in MgB_2 filaments prepared from commercial pure B fibers. In Fig. 4, an electron micrograph is shown in end view for the long time limit where a 100 μm diameter fiber that has been reacted in Mg vapor at $950^\circ C$ for 78 h . The white core of W_2B_5 in the center is measured here to be 16.7 μm in diameter and the starting 100 μm boron fiber has grown to about 135 μm diameter as Mg is added. There is a small patch of MgB_4 in the upper left quadrant, and there the void pattern is very typical of all the samples grown.

III. TITANIUM DOPING

In the early experiments with *CVD* doping of *B* with *Ti*, the material was deposited on either a *W* substrate or a *C* coated substrate, and a preliminary report of this work has been presented.¹⁸ Most of the experiments reported here, however, were done by simultaneously depositing *B* and a few percent *Ti* on a continuous 75 μm diameter silicon carbide filament coated with several micrometers of glassy carbon (commercially available as SCS-9A). Deposition was accomplished in a reactor similar to that used for commercial boron filament production.¹⁹ The substrate filament was drawn through the reactor at 100 mm/s ; the filament in the reactor was resistively heated to peak temperatures of approximately 1100°C. The reactant gas was predominantly a stoichiometric mixture of hydrogen and boron trichloride at atmospheric pressure. Titanium dopant was added by bubbling the hydrogen component through titanium tetrachloride held at 0°C. The resulting partial pressure of titanium tetrachloride was approximately 2×10^{-3} bar. The doped boron-coated substrate was spooled continuously upon emerging from the reactor. An X-ray powder diffraction study of the resulting fibers before *Mg* reaction indicates comparable amounts of *TiB* and *TiB₂* as well as a small amount of *B₁₀C*. Subsequent reaction with *Mg* vapor produced *MgB₂* filaments with precipitated *TiB₂*. The intensity of the X-ray lines indicates less *TiB* in the reacted fiber than in the unreacted fiber.

A series of samples were prepared in which *B* and *Ti* were co-deposited on the carbon surface with thicknesses of 4 μm , 6 μm and 10 μm . After reaction in *Mg* vapor at both 950°C for 2 *h* and at 1100°C for 30 *min*, the conversion of *B* to *MgB₂* was complete.¹⁸ An extensive study of the *Ti* distribution was undertaken with *EDS* in a *SEM* where the beam size was approximately 1 micrometer. Generally, the *Ti/Mg* ratio was in the neighborhood of 9% in the bulk of the material. This is illustrated in Fig. 5 where a sample with 6 μm of *B* $\sim$ 9%*Ti* is deposited on a carbon coated substrate. There are two regions of the sample, however, that are consistently high *Ti*. This is near the *C* substrate and near the outer surface. Reaction kinetics indicate that the deposition of *Ti* compared to *B* is

higher at lower temperatures. Hence, as the fiber moves through the deposition zone, the Ti deposition will be faster than that of boron during the initial warm-up on entrance to the hottest regions and during the cool-down as the fiber exits the hottest regions. Another specimen illustrated in Fig. 6 shows a $4\ \mu m$ thick layer of $B \sim 9\%Ti$. Here, there are two rather distinct regions of Ti content. In most of the boron layer, the Ti content is about 9%, but sometimes there are bright lacy regions where the Ti content is about 30%. By studying polished regions of the MgB_2 with polarized light, the grain structure is readily apparent. If a particular region of the sample is studied both with polarized light and with *SEM* with *EDS* area maps, the Ti is found to be spread throughout the grains. The grain boundaries are not seen to be high in Ti on these area maps. This result differs from the beautiful decoration of MgB_2 grain boundaries with TiB_2 seen for samples made from powders in solid state reactions.¹¹ Titanium doping using *CVD* methods gives a dispersion of TiB_2 in MgB_2 that is different from that seen for solid state reaction of powders.

IV. CRITICAL CURRENT DENSITIES

The addition of Ti greatly enhances the J_c values if the level of Ti doping is properly adjusted. As reported previously, anything approaching a Ti/Mg ratio of 1 is far too much Ti .¹⁸ The volume fraction of superconductor is reduced by half, and the value of T_c drops to about 20 K . In accord with earlier findings,⁹ a Ti/Mg ratio in the neighborhood of 0.09 greatly enhances both J_c and H_{irr} while depressing T_c only a few degrees. At 5 K and self field, J_c increases from about $4 \times 10^5\ A/cm^2$ for pure MgB_2 to about $2 \times 10^6\ A/cm^2$ for the 9% Ti sample. With increasing magnetic field, J_c crosses 10,000 A/cm^2 at 5 T with 9% Ti as compared to 1.4 T for the pure MgB_2 sample as shown by the solid triangles in Fig. 7. At 25 K , the 9% Ti sample crosses 10,000 A/cm^2 at about 1.3 T compared with the pure MgB_2 sample which crosses 10,000 A/cm^2 at 0.9 T .

In addition to simply adding Ti to the boron fibers, there is a great deal of optimization that can yet be done. When the starting $B_{0.91}Ti_{0.09}$ fibers are prepared, there is a large

amount of both TiB and TiB_2 in the boron. During the reaction to form MgB_2 , some of the TiB is converted to TiB_2 , and there may be some migration of C from the substrate into the sample. Much more needs to be learned about both of these processes. An optimization of J_c at 25 K with $B_{0.91}Ti_{0.09}$ ¹⁸ shows that a reaction time of 30 *min* is best for a reaction temperature of 1100°C and a reaction time of 2 *h* is best for a reaction temperature of 950°C. An optimization for J_c values at 5 K , shown in Fig. 8, indicates that 30 *min* at 1100°C gives the highest J_c values.

V. THICKNESS DEPENDENCE

For pure B fibers deposited on a 15 μm W core, a series of B fibers having diameters ranging from 100 μm to 300 μm were fully reacted in Mg vapor at 950°C for times ranging from 2 *h* to 48 *h*. In all cases, the reaction to form MgB_2 increases the fiber diameter by about 35%. At 5 K and self field, the J_c values range from 700,000 A/cm^2 to 300,000 A/cm^2 and have a magnetic field dependence similar to those shown in Fig. 1. At 25 K , the data of Fig. 9 indicate that $J_c(H)$ nearly is independent of diameter. To the accuracy and reproducibility of the measurement, all of these fiber diameters have the same J_c vs H plots.

For the $B9\%Ti$ deposited on a carbon coated substrate, samples having a thickness of 4 μm , 6 μm , and 10 μm have been studied. We expected a difference in J_c among these samples caused by different amounts of C impurity or caused by a different distribution of TiB or TiB_2 during the Ti and B deposition on the C substrate. These are relatively small effects as shown on Fig. 10. These data were taken for samples reacted at 1100°C for 15 *min*. A reaction time less than the 30 *min* for optimum J_c was intended to limit possible diffusion of C from the substrate. In broad terms, the 5 K J_c data are about 3×10^6 A/cm^2 at low field and the J_c data cross the 10,000 A/cm^2 line at about 4 T . There is not a large thickness dependence of J_c , but at high fields, the thicker samples seem to show a higher J_c values. At low fields, the thinner samples seem to show the higher J_c values. Similar data

have been reported elsewhere.¹⁸ There is lots of room for improvement by optimizing the *Ti* content, the reaction temperatures, and the reaction times.

VI. CONCLUSIONS

Co-deposition of boron along with the desired impurities offers a distinctive method of doping. When these doped fibers are converted to MgB_2 by heating in Mg vapor, the resulting TiB_2 is distributed relatively uniformly within the grains. This distribution is quite different from MgB_2 samples prepared by solid state diffusion of mixed powders. Critical current densities of 2 to 5 million A/cm^2 are obtained at 5 K and self field. Critical current densities of 10,000 A/cm^2 are obtained at 25 K and 1.4 T .

A number of important variables are still not well understood. Improvement is needed in the control of the distribution of TiB_2 , and a more thorough study of carbon doping needs to be undertaken so that a quantitative contrast can be developed between the effects of C substitution in the lattice with the effects of TiB_2 precipitates. Although there is a fairly wide sweet spot for the reaction of doped B fibers to form doped MgB_2 , there is lots of room for improvement. The performance of the conductor can yet be optimized with respect to Ti content and carbon content as well as the time and temperature of Mg reaction.

VII. ACKNOWLEDGMENTS

Work is supported by the U.S. Department of Energy, Basic Energy Sciences, Office of Science, through the Ames Laboratory under Contract No. W-7405-Eng-82.

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FIGURES

FIG. 1. Comparison of J_c values for pure MgB_2 made from 100 μm boron fibers with a W_2B_5 core and 25 μm of pure boron on a carbon substrate at both 5 K and 25 K .

FIG. 2. Micrograph and EDS line scan showing the initial diffusion of Mg into a 100 μm diameter boron fiber. The white core is W_2B_5

FIG. 3. Typical section of a MgB_2 filament that is fully reacted. The white area in the center is a portion of the W_2B_5 core. The darker gray areas are MgB_4 as indicated by the 30% drop in *EDS* scan intensity.

FIG. 4. Typical end view of a MgB_2 filament prepared from a 100 μm diameter pure B fiber. The dark gray area in the upper left quadrant is MgB_4 and void area is typical.

FIG. 5. A section of 4 μm thick layer of $B9\%Ti$ deposited on a C substrate and reacted at 1100°C for 15 *min*. The light and dark regions reflect a change in Ti/Mg ratio. High Ti near the MgB_2 inner and outer surfaces is typical.

FIG. 6. A section of a 4 μm thick layer of $B9\%Ti$ deposited on a C substrate in which the Ti is high in the outer half and about 50% as high in the inner half.

FIG. 7. Comparison of the J_c data for a sample made from 25 μm of pure boron on a carbon substrate with a sample made from 10 μm of $B_{0.91}Ti_{0.09}$ on a carbon substrate at both 5 K and 25 K . Both J_c and H_{c2} are increased substantially by adding a few percent Ti .

FIG. 8. Optimization of J_c vs time at 1100°C and 9% Ti .

FIG. 9. J_c data for various wire diameters for pure B fiber at 25 K .

FIG. 10. J_c data for various thicknesses of $B_{0.91}C_{0.09}$ at 5 K .

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